

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S53	359	titanium near10 (diffusion near (prevention or preventing or barrier)) near10 aluminum	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:37
S54	25	electrode near10 titanium near10 (diffusion near (prevention or preventing or barrier)) near10 aluminum	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:38
S55	6	electrode near10 titanium near10 (diffusion near (prevention or preventing or barrier)) near10 aluminum and (tft or (thin adj film adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:39
S56	1	(electrode near10 titanium near10 (diffusion near (prevention or preventing or barrier)) near10 aluminum near10 (interpose or interposed or interposing or sandwich or sandwiching or sandwiched)) and (tft or (thin adj film adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:40
S57	2	(titanium near10 (diffusion near (prevention or preventing or barrier)) near10 aluminum near10 (interpose or interposed or interposing or sandwich or sandwiching or sandwiched)) and (tft or (thin adj film adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:40
S58	4	(titanium near10 (diffusion near (prevention or preventing or barrier)) near10 aluminum near10 (between or interpose or interposed or interposing or sandwich or sandwiching or sandwiched)) and (tft or (thin adj film adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:41
S59	2	(titanium near5 (diffusion near (prevention or preventing or barrier)) near5 aluminum near5 (between or interpose or interposed or interposing or sandwich or sandwiching or sandwiched)) and (tft or (thin adj film adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:42

S60	3	((titanium near2 (film or layer)) near5 (diffusion near (prevention or preventing or barrier)) near5 aluminum near5 (between or interpose or interposed or interposing or sandwich or sandwiching or sandwiched)) and (tft or (thin adj film adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:42
S61	2	((titanium near2 (film or layer)) near5 (diffusion near (prevention or preventing or barrier)) near5 (aluminum near2 (film or layer)) near5 (between or interpose or interposed or interposing or sandwich or sandwiching or sandwiched)) and (tft or (thin adj film adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:43
S62	1	((titanium near2 (film or layer)) near10 (diffusion near (prevention or preventing or barrier)) near10 (aluminum near2 (film or layer)) near10 (between or interpose or interposed or interposing or sandwich or sandwiching or sandwiched)).clm. and (tft or (thin adj film adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:43
S63	2	((titanium near2 (film or layer)) near10 (diffusion near (prevention or preventing or barrier)) near10 (aluminum near2 (film or layer)) near10 (between or interpose or interposed or interposing or sandwich or sandwiching or sandwiched)).ti,ab,clm. and (tft or (thin adj film adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:43

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S69	1	(titanium near2 (layer or film)). clm. and (aluminum near2 (layer or film)).clm. and (diffusion adj (barrier or preventing or prevention) adj (film or layer)). clm. and (tft or (thin adj film adj transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:45
S70	1	(titanium near2 (layer or film)). clm. and (aluminum near2 (layer or film)).clm. and (diffusion adj (barrier or preventing or prevention) adj (film or layer)) and (tft or (thin adj film adj transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:45
S71	1	(titanium near2 (layer or film)) with (aluminum near2 (layer or film)) with (diffusion adj (barrier or preventing or prevention) adj (film or layer)) and (tft or (thin adj film adj transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:46
S72	3	(titanium near2 (layer or film)) with (aluminum near2 (layer or film)) with (diffusion adj (barrier or preventing or prevention) adj (film or layer)) and (tft or (thin adj film adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 16:32